

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S11 4	290	S112 AND S113	US-PGPUB; USPAT	OR	OFF	2006/01/11 15:42
S11 3	12280	(438/253,254,255,256,257,700, 702,704,706,710,719,723,724, 745,753,770).CCLS.	US-PGPUB; USPAT	OR	OFF	2006/01/11 15:42
S79	11841	(438/253,254,255,256,257,700, 702,704,706,710,719,723,724, 745,753,770).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/11 15:42
S11 2	1976	S111 AND (side\$1wall\$4 NEAR20 spacer\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/11 15:38
S11 1	7324	S110 AND (second\$4 NEAR20 ((poly\$1silicon\$4 NEAR20 (layer\$4 OR film\$4) NEAR20 gate\$4)))	US-PGPUB; USPAT	OR	OFF	2006/01/11 15:38
S11 0	30017	transistor\$4 AND (poly\$1silicon\$4 NEAR20 (layer\$4 OR film\$4) NEAR20 gate\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/11 15:37
S74	34	("5310693").URPN.	USPAT	OR	OFF	2006/01/11 15:36
S10 9	160	(side\$wall\$4 NEAR20 spacer\$4) NEAR20 (etch\$1mask\$4 OR (etch\$4 ADJ mask\$4) or (etch\$4 NEAR5 mask\$4)) NEAR20 poly\$1silicon\$4	US-PGPUB; USPAT	OR	OFF	2006/01/11 14:59
S97	1082	(side\$wall\$4 NEAR20 spacer\$4) NEAR20 (etch\$1mask\$4 OR (etch\$4 ADJ mask\$4) or (etch\$4 NEAR5 mask\$4))	US-PGPUB; USPAT	OR	OFF	2006/01/11 14:58
S10 8	209	S106 AND (poly\$1silicon\$4 NEAR20 (mask\$4 OR etch\$1mask\$4))	US-PGPUB; USPAT	OR	OFF	2006/01/11 14:33
S10 7	209	S106 AND (poly\$1silicon\$4 NEAR20 mask\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/11 14:32
S10 6	388	S105 AND ((spacer\$4 OR side\$1wall\$4) NEAR20 mask\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/11 14:29
S10 5	1090	S104 AND (spacer\$4 OR side\$1wall\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/11 14:29
S10 4	2436	S103 AND (memor\$4 NEAR20 non\$1volatil\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/11 14:29
S10 3	3079	S102 AND (tunnel\$4 NEAR4 oxide\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/11 14:29
S10 2	8097	S101 AND memor\$4	US-PGPUB; USPAT	OR	OFF	2006/01/11 14:29
S10 1	9655	S100 AND (float\$4 NEAR20 gate\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/11 14:29
S10 0	84186	S99 AND ((field\$4 NEAR10 oxide\$4) OR FOX OR isolat\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/11 14:29

S99	175274	(metal\$4 NEAR10 oxide\$4 NEAR semi\$1conduct\$4) OR MOS OR FET OR MOS\$1FET	US-PGPUB; USPAT	OR	OFF	2006/01/11 14:29
S95	388	S94 AND ((spacer\$4 OR side\$1wall\$4) NEAR20 mask\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/11 14:29
S98	134	S97 AND ((lithograph\$4 OR photo\$1lithograph\$4) NEAR20 limit\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/06 09:44
S96	44	S95 AND ((lithograph\$4 OR photo\$1lithograph\$4) NEAR20 limit\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/06 09:44
S85	134	S84 AND ((lithograph\$4 OR photo\$1lithograph\$4) NEAR20 limit\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/06 09:40
S94	1088	S93 AND (spacer\$4 OR side\$1wall\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/06 09:27
S34	819	S33 AND (spacer\$4 OR side\$1wall\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/06 09:26
S93	2432	S92 AND (memor\$4 NEAR20 non\$1volatile\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/06 09:25
S25	1964	S23 AND (memor\$4 NEAR20 non\$1volatile\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/06 09:25
S92	3074	S91 AND (tunnel\$4 NEAR4 oxide\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/06 09:24
S91	8086	S90 AND memor\$4	US-PGPUB; USPAT	OR	OFF	2006/01/06 09:24
S23	2498	S22 AND (tunnel\$4 NEAR4 oxide\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/06 09:24
S22	6499	S21 AND memor\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/06 09:24

S90	9643	S89 AND (float\$4 NEAR20 gate\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/06 09:23
S89	84130	S88 AND ((field\$4 NEAR10 oxide\$4) OR FOX OR isolat\$4)	US-PGPUB; USPAT	OR	OFF	2006/01/06 09:23
S30	7736	S29 AND (float\$4 NEAR20 gate\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/06 09:23
S88	175152	(metal\$4 NEAR10 oxide\$4 NEAR semi\$1conduct\$4) OR MOS OR FET OR MOS\$1FET	US-PGPUB; USPAT	OR	OFF	2006/01/06 09:22
S29	70917	S28 AND ((field\$4 NEAR10 oxide\$4) OR FOX OR isolat\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/06 09:22
S28	197641	(metal\$4 NEAR10 oxide\$4 NEAR semi\$1conduct\$4) OR MOS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/06 09:21
S86	18	S85 AND S79	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/15 13:19
S84	4415	S83 AND (memor\$4 NEAR20 non\$1volatil\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/15 12:56
S83	6504	S82 AND memor\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/15 12:56
S82	7743	S81 AND (float\$4 NEAR20 gate\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/15 12:56

S81	71021	S80 AND ((field\$4 NEAR10 oxide\$4) OR FOX OR isolat\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/15 12:56
S80	198065	(metal\$4 NEAR10 oxide\$4 NEAR semi\$1conduct\$4) OR MOS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/15 12:56
S78	84	S77 AND (spacer\$4 NEAR20 multiple\$4 NEAR20 layer\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/15 08:49
S77	17594	S76 AND spacer\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/15 08:48
S76	198065	(metal\$4 NEAR10 oxide\$4 NEAR semi\$1conduct\$4) OR MOS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/15 08:48
S75	4	("5510286").URPN.	USPAT	OR	OFF	2005/08/10 15:44
S73	5	("6027972").URPN.	USPAT	OR	OFF	2005/08/10 15:19
S72	11	("4513397" "4558339" "5100818" "5225362" "5310693" "5612237" "5750428" "5773343" "5817557" "5837583" "5854501").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/08/10 15:16
S71	11	("5019879" "5886379" "5962889" "5973353" "6015984" "6218246" "6252271" "6309926" "6380035" "6380582" "6486508").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/08/10 15:06
S66	1	("6583008").PN.	USPAT; USOCR	OR	OFF	2005/08/10 15:06
S65	8	("5915178" "5970354" "6228695" "6312989" "6380583" "6583008" "6627524" "6653188").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/08/10 14:16

S64	1	("6881629").PN.	USPAT; USOCR	OR	OFF	2005/08/10 13:57
S60	4	"6399442"	USPAT	OR	OFF	2005/08/10 13:45
S61	9	("5108939" "5352618" "5516713" "5953254" "6156610" "6174771" "6255172" "6316316" "6369422").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/08/10 13:25
S51	134	S44 AND ((lithograph\$4 OR photo\$1lithograph\$4) NEAR20 limit\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/10 12:30
S52	5	("6027972").URPN.	USPAT	OR	OFF	2005/08/10 11:01
S45	5	((("5915178") or ("6380583") or ("6403494") or ("6326660") or ("5643814"))).PN.	USPAT; USOCR	OR	OFF	2005/08/10 10:33
S44	4412	S42 AND (memor\$4 NEAR20 non\$1volatile\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/10 10:32
S33	1964	S32 AND (memor\$4 NEAR20 non\$1volatile\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/10 10:30
S42	6499	S41 AND memor\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/10 10:29
S41	7736	S40 AND (float\$4 NEAR20 gate\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/10 10:29
S40	70917	S39 AND ((field\$4 NEAR10 oxide\$4) OR FOX OR isolat\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/10 10:29

S39	197641	(metal\$4 NEAR10 oxide\$4 NEAR semi\$1conduct\$4) OR MOS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/10 10:29
S26	819	S25 AND (spacer\$4 OR side\$1wall\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/10 10:29
S38	2	"EP 1387395"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/10 10:28
S2	3	(("20010041309") or ("6242795") or ("5893748")).PN.	US-PGPUB; USPAT	OR	OFF	2005/08/10 10:27
S37	147	S36 AND planariz\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/10 08:53
S36	293	S35 AND ((spacer\$4 OR side\$1wall\$4) NEAR20 nitride\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/10 08:53
S35	527	S34 AND ((spacer\$4 OR side\$1wall\$4) NEAR20 (remov\$4 OR etch\$4))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/10 08:50
S32	2498	S31 AND (tunnel\$4 NEAR4 oxide\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/10 08:50
S31	6499	S30 AND memor\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/10 08:50

S20	70917	S3 AND ((field\$4 NEAR10 oxide\$4) OR FOX OR isolat\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/09 18:30
S21	7736	S20 AND (float\$4 NEAR20 gate\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/09 18:27
S3	197641	(metal\$4 NEAR10 oxide\$4 NEAR semi\$1conduct\$4) OR MOS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/09 17:58